

### FEATURES

- Low On-State Resistance
- Low  $Q_G$  and Capacitance Losses
- RoHS Compliant and Halogen Free

### PRODUCT SUMMARY

| $R_{DS(on)}$ (TYP)<br>$V_{GS} = 10V$ | $R_{DS(on)}$ (MAX)<br>$V_{GS} = 10V$ | $I_D$ (MAX)<br>$T_C = +25^\circ C$ |
|--------------------------------------|--------------------------------------|------------------------------------|
| 1.1m $\Omega$                        | 1.4m $\Omega$                        | 165A                               |

### ABSOLUTE MAXIMUM RATINGS

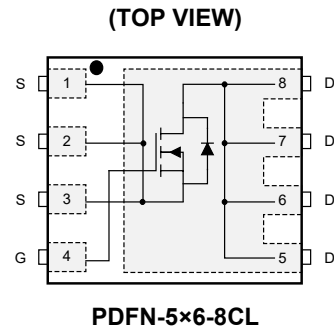
| PARAMETER                            |                         | SYMBOL           | VALUE       | UNITS |
|--------------------------------------|-------------------------|------------------|-------------|-------|
| Drain-to-Source Voltage              |                         | V <sub>DS</sub>  | 30          | V     |
| Gate-to-Source Voltage               |                         | V <sub>GS</sub>  | ±20         | V     |
| Drain Current <sup>(1)</sup>         | T <sub>C</sub> = +25°C  | I <sub>D</sub>   | 165         | A     |
|                                      | T <sub>C</sub> = +100°C |                  | 105         |       |
|                                      | T <sub>A</sub> = +25°C  |                  | 30          |       |
|                                      | T <sub>A</sub> = +70°C  |                  | 24          |       |
| Drain Current (Pulse) <sup>(2)</sup> |                         | I <sub>DM</sub>  | 660         | A     |
| Total Dissipation                    | T <sub>C</sub> = +25°C  | P <sub>D</sub>   | 78          | W     |
|                                      | T <sub>C</sub> = +100°C |                  | 31          |       |
|                                      | T <sub>A</sub> = +25°C  |                  | 2.5         |       |
|                                      | T <sub>A</sub> = +70°C  |                  | 1.6         |       |
| Avalanche Current <sup>(3)</sup>     |                         | I <sub>AS</sub>  | 83          | A     |
| Avalanche Energy <sup>(3)</sup>      |                         | E <sub>AS</sub>  | 344.5       | mJ    |
| Junction Temperature                 |                         | T <sub>J</sub>   | +150        | °C    |
| Storage Temperature Range            |                         | T <sub>STG</sub> | -55 to +150 | °C    |
| Lead Temperature (Soldering, 10s)    |                         |                  | +260        | °C    |

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

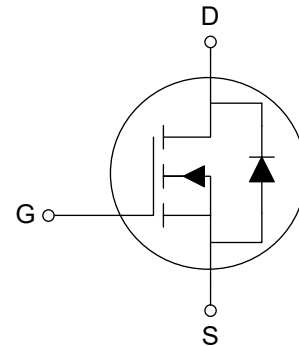
#### NOTES:

1. The current will be limited by PCB, thermal design and operating temperature.
2.  $t_{PULSE} < 10\mu s$ .
3. Parts are 100% tested at  $V_{GS} = 10V$ ,  $I_L = 58.7A$ , and  $E_{AS} = 173mJ$ .

### PIN CONFIGURATION



### EQUIVALENT CIRCUIT



### APPLICATIONS

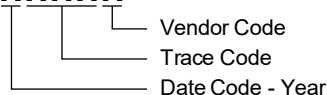
- Load Switch
- High-Speed Line Driver
- Power Tool
- Motor Application

**PACKAGE/ORDERING INFORMATION**

| MODEL      | PACKAGE DESCRIPTION | SPECIFIED TEMPERATURE RANGE | ORDERING NUMBER     | PACKAGE MARKING           | PACKING OPTION      |
|------------|---------------------|-----------------------------|---------------------|---------------------------|---------------------|
| SGMNQ11430 | PDFN-5×6-8CL        | -55°C to +150°C             | SGMNQ11430TPDA8G/TR | SGM2BG<br>TPDA8<br>XXXXXX | Tape and Reel, 4000 |

**MARKING INFORMATION**

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.

**XXXXXX**

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

**DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

**THERMAL RESISTANCE**

| PARAMETER                                             | SYMBOL          | TYP | UNITS |
|-------------------------------------------------------|-----------------|-----|-------|
| Junction-to-Ambient Thermal Resistance <sup>(1)</sup> | $R_{\theta JA}$ | 49  | °C/W  |
| Junction-to-Case Thermal Resistance                   | $R_{\theta JC}$ | 1.6 | °C/W  |

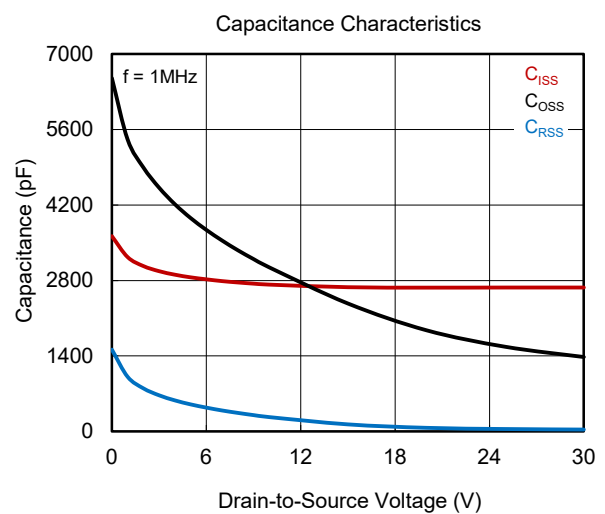
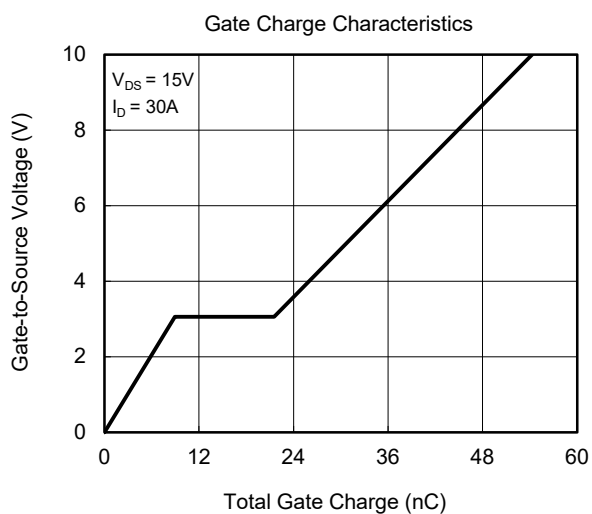
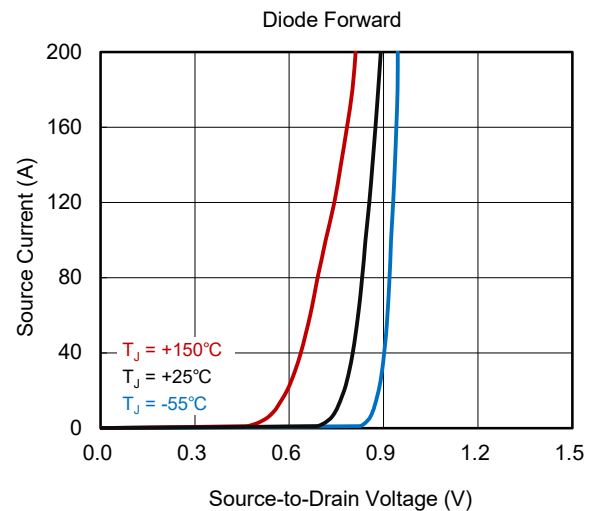
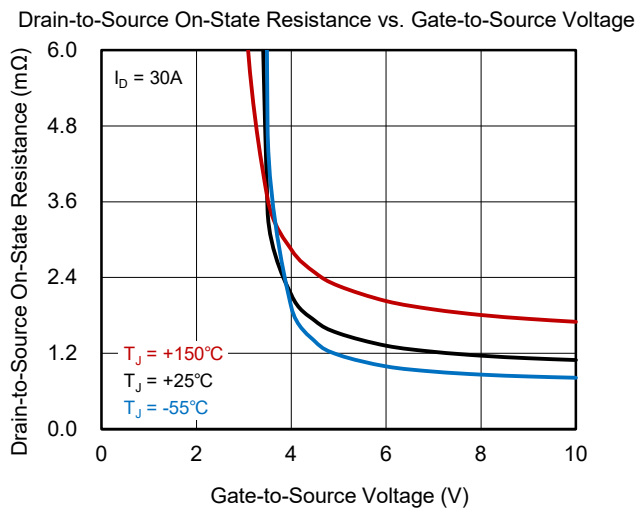
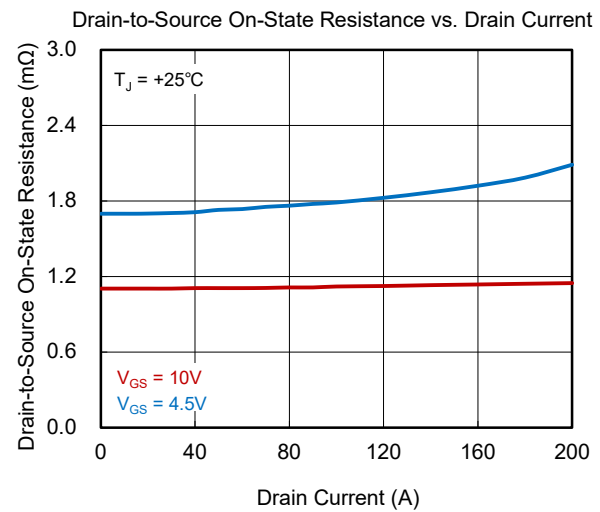
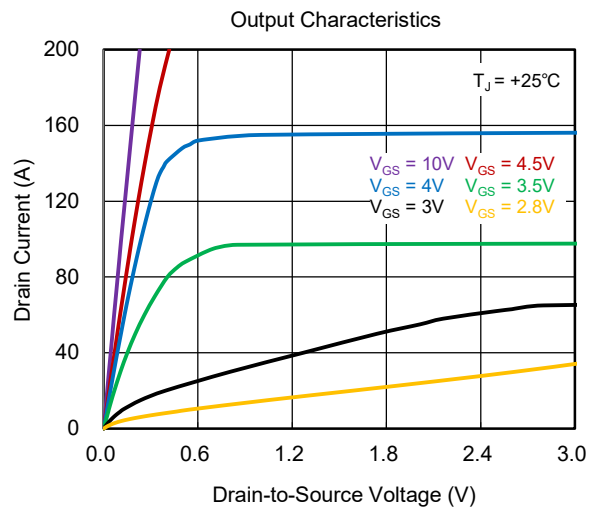
NOTE: 1.  $R_{\theta JA}$  is determined with the device mounted on one square inch of copper pad, 2oz copper on FR4 board.

## ELECTRICAL CHARACTERISTICS

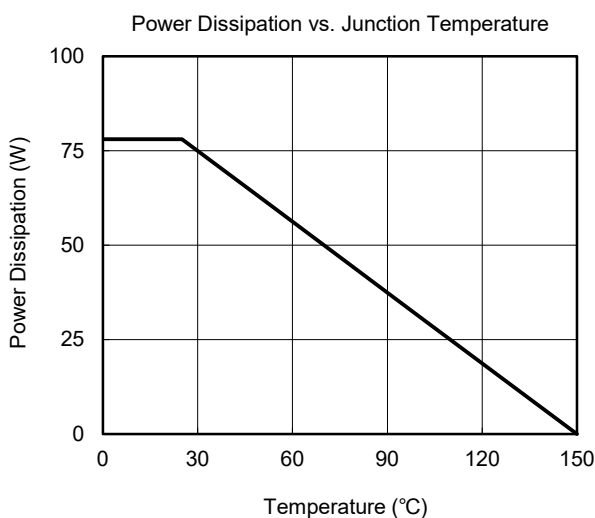
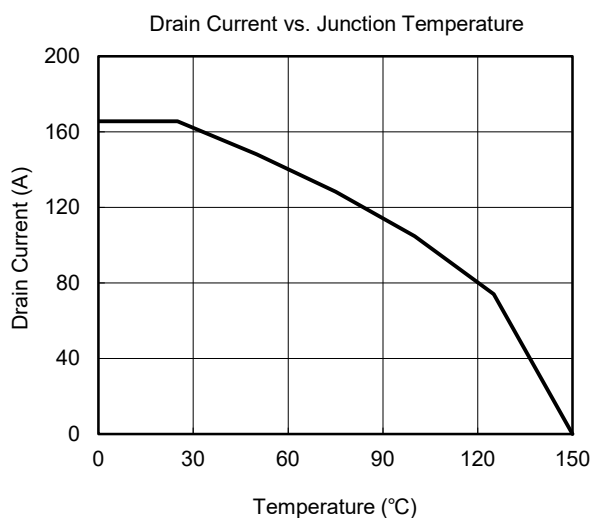
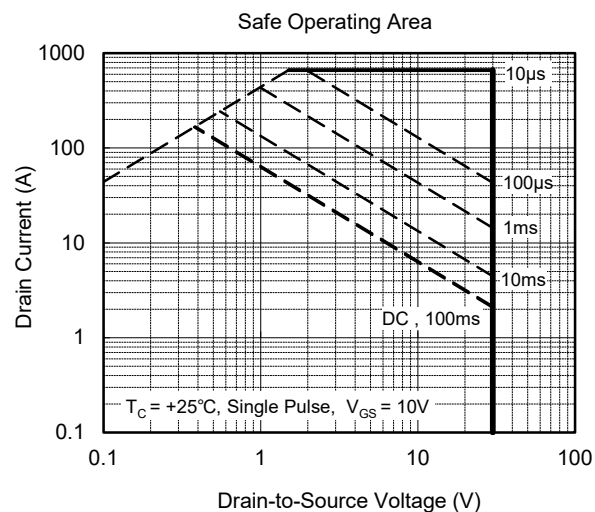
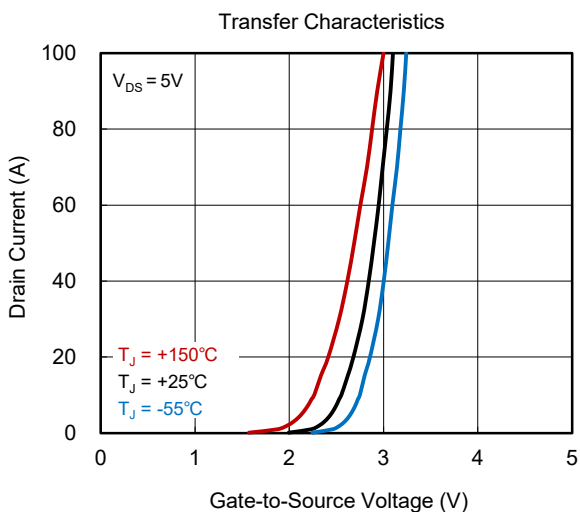
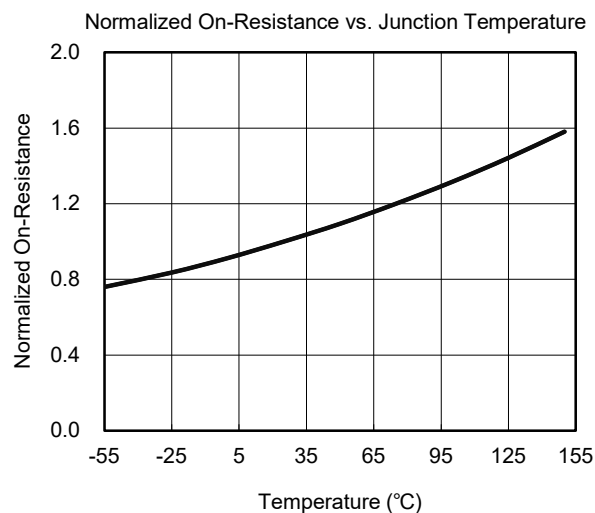
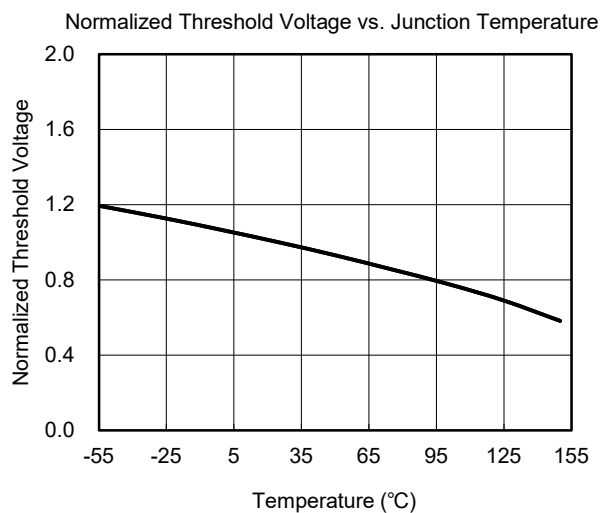
(T<sub>A</sub> = +25°C, unless otherwise noted.)

| PARAMETER                           | SYMBOL              | CONDITIONS                                                                              |                        | MIN | TYP  | MAX  | UNITS |
|-------------------------------------|---------------------|-----------------------------------------------------------------------------------------|------------------------|-----|------|------|-------|
| Static OFF Characteristics          |                     |                                                                                         |                        |     |      |      |       |
| Drain-to-Source Breakdown Voltage   | V <sub>BR_DSS</sub> | V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA                                            |                        | 30  |      |      | V     |
| Zero Gate Voltage Drain Current     | I <sub>DSS</sub>    | V <sub>GS</sub> = 0V, V <sub>DS</sub> = 24V                                             |                        |     |      | 1    | μA    |
| Gate-to-Source Leakage Current      | I <sub>GSS</sub>    | V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V                                            |                        |     |      | ±100 | nA    |
| Static ON Characteristics           |                     |                                                                                         |                        |     |      |      |       |
| Gate-to-Source Threshold Voltage    | V <sub>GS_TH</sub>  | V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250μA                              |                        | 1   | 1.7  | 2.2  | V     |
| Drain-to-Source On-State Resistance | R <sub>DSON</sub>   | I <sub>D</sub> = 30A                                                                    | V <sub>GS</sub> = 10V  |     | 1.1  | 1.4  | mΩ    |
|                                     |                     |                                                                                         | V <sub>GS</sub> = 4.5V |     | 1.7  | 2.2  |       |
| Forward Transconductance            | g <sub>FS</sub>     | V <sub>DS</sub> = 5V, I <sub>D</sub> = 30A                                              |                        |     | 60   |      | S     |
| Gate Resistance                     | R <sub>G</sub>      | V <sub>GS</sub> = 0V, V <sub>DS</sub> = 0V, f = 1MHz                                    |                        |     | 0.6  |      | Ω     |
| Diode Characteristics               |                     |                                                                                         |                        |     |      |      |       |
| Diode Forward Voltage               | V <sub>F_SD</sub>   | V <sub>GS</sub> = 0V, I <sub>S</sub> = 30A                                              |                        |     | 0.8  | 1.2  | V     |
| Reverse Recovery Time               | t <sub>RR</sub>     | V <sub>GS</sub> = 0V, I <sub>S</sub> = 30A, di/dt = 100A/μs                             |                        |     | 60   |      | ns    |
| Reverse Recovery Charge             | Q <sub>RR</sub>     |                                                                                         |                        |     | 82   |      | nC    |
| Dynamic Characteristics             |                     |                                                                                         |                        |     |      |      |       |
| Input Capacitance                   | C <sub>ISS</sub>    | V <sub>GS</sub> = 0V, V <sub>DS</sub> = 15V, f = 1MHz                                   |                        |     | 2750 |      | pF    |
| Output Capacitance                  | C <sub>OSS</sub>    |                                                                                         |                        |     | 2285 |      |       |
| Reverse Transfer Capacitance        | C <sub>RSS</sub>    |                                                                                         |                        |     | 120  |      |       |
| Total Gate Charge                   | Q <sub>G</sub>      | V <sub>DS</sub> = 15V, I <sub>D</sub> = 30A                                             | V <sub>GS</sub> = 10V  |     | 54.3 |      | nC    |
|                                     |                     |                                                                                         | V <sub>GS</sub> = 4.5V |     | 27.6 |      |       |
| Gate-to-Source Charge               | Q <sub>GS</sub>     | V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 15V, I <sub>D</sub> = 30A                     |                        |     | 9    |      |       |
| Gate-to-Drain Charge                | Q <sub>GD</sub>     |                                                                                         |                        |     | 12.6 |      |       |
| Switch Characteristics              |                     |                                                                                         |                        |     |      |      |       |
| Turn-On Delay Time                  | t <sub>D_ON</sub>   | V <sub>GS</sub> = 10V, V <sub>DS</sub> = 15V, I <sub>D</sub> = 30A, R <sub>G</sub> = 3Ω |                        |     | 10.2 |      | ns    |
| Rise Time                           | t <sub>R</sub>      |                                                                                         |                        |     | 47   |      |       |
| Turn-Off Delay Time                 | t <sub>D_OFF</sub>  |                                                                                         |                        |     | 31.6 |      |       |
| Fall Time                           | t <sub>F</sub>      |                                                                                         |                        |     | 11.8 |      |       |

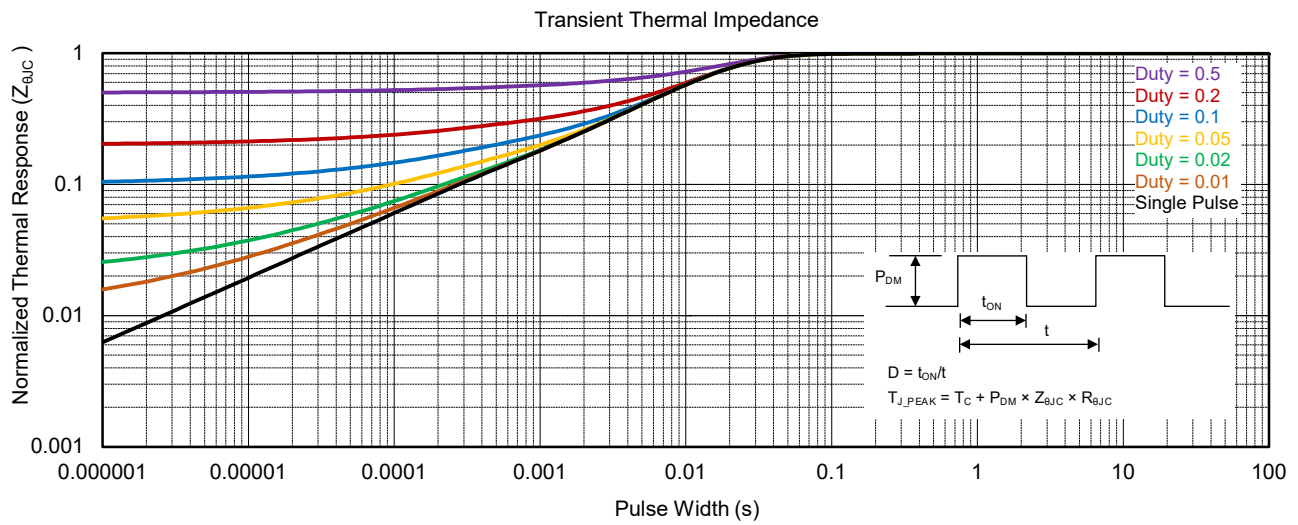
## TYPICAL PERFORMANCE CHARACTERISTICS



## TYPICAL PERFORMANCE CHARACTERISTICS (continued)



## TYPICAL PERFORMANCE CHARACTERISTICS (continued)



## REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

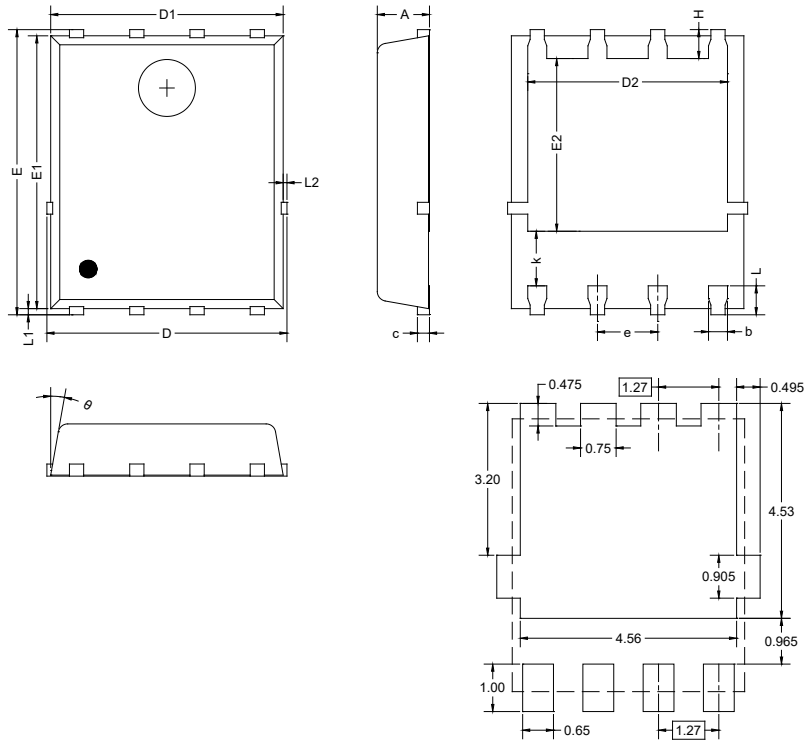
## Changes from Original to REV.A (SEPTEMBER 2026)

Page

Changed from product preview to production data.....All

## PACKAGE OUTLINE DIMENSIONS

### PDFN-5×6-8CL



RECOMMENDED LAND PATTERN (Unit: mm)

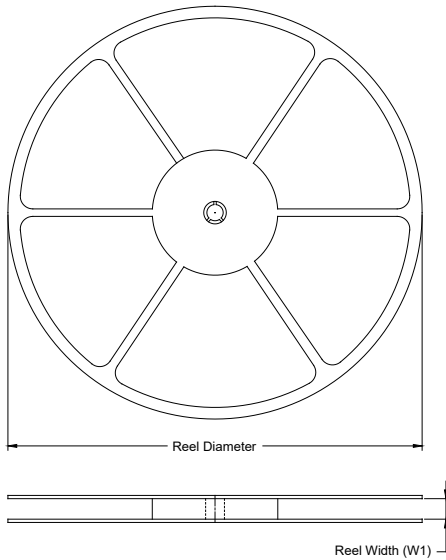
| Symbol | Dimensions In Millimeters |       |       |
|--------|---------------------------|-------|-------|
|        | MIN                       | NOM   | MAX   |
| A      | 0.900                     | 1.100 | 1.200 |
| b      | 0.300                     | 0.400 | 0.550 |
| c      | 0.150                     | 0.250 | 0.350 |
| D      | 4.800                     | -     | 5.400 |
| D1     | 4.800                     | 4.900 | 5.000 |
| D2     | 4.000                     | 4.210 | 4.400 |
| E      | 5.900                     | 6.000 | 6.250 |
| E1     | 5.650                     | 5.750 | 5.850 |
| E2     | 3.500                     | 3.640 | 3.900 |
| e      | 1.270 BSC                 |       |       |
| H      | 0.350                     | 0.610 | 0.710 |
| k      | 1.100                     | -     | -     |
| L      | 0.400                     | 0.610 | 0.710 |
| L1     | 0.050                     | 0.130 | 0.250 |
| L2     | -                         | -     | 0.220 |
| θ      | 8°                        | 10°   | 12°   |

NOTE: This drawing is subject to change without notice.

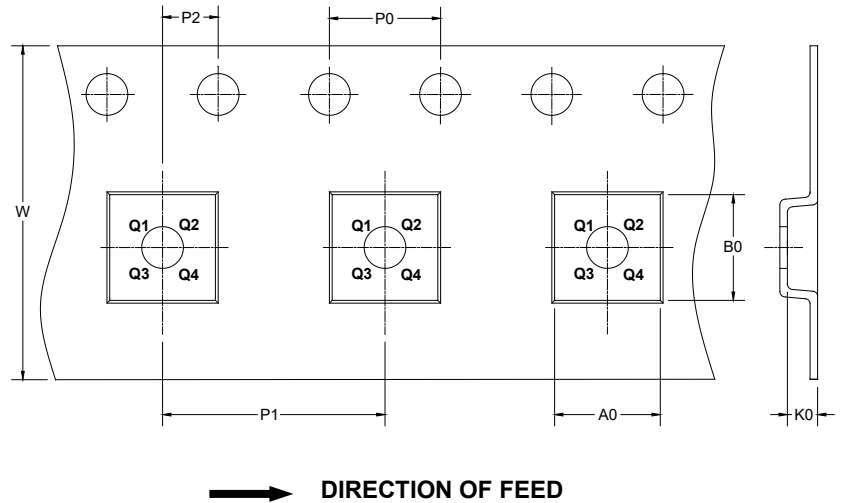
# PACKAGE INFORMATION

## TAPE AND REEL INFORMATION

### REEL DIMENSIONS



### TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

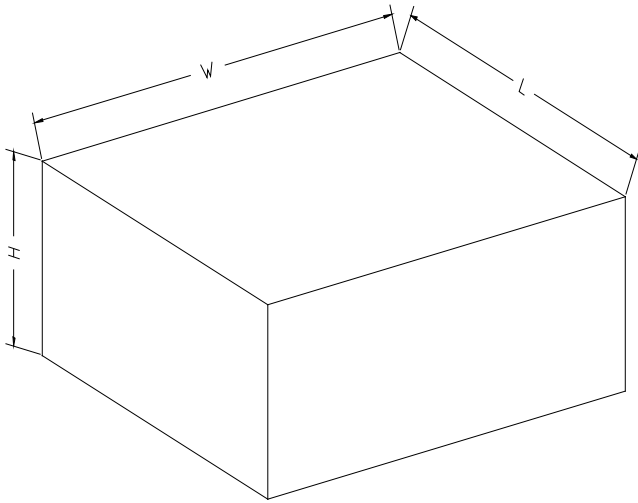
### KEY PARAMETER LIST OF TAPE AND REEL

| Package Type | Reel Diameter | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P0 (mm) | P1 (mm) | P2 (mm) | W (mm) | Pin1 Quadrant |
|--------------|---------------|--------------------|---------|---------|---------|---------|---------|---------|--------|---------------|
| PDFN-5×6-8CL | 13"           | 12.4               | 6.45    | 5.30    | 1.40    | 4.0     | 8.0     | 2.0     | 12.0   | Q1            |

DD0001

## PACKAGE INFORMATION

### CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

### KEY PARAMETER LIST OF CARTON BOX

| Reel Type | Length<br>(mm) | Width<br>(mm) | Height<br>(mm) | Pizza/Carton |
|-----------|----------------|---------------|----------------|--------------|
| 13"       | 386            | 280           | 370            | 5            |

DD0002